



DC - DC HIGH VOLTAGE SOLID STATE RELAYS **SDD - 1200- 25/40 SERIES**

Features

Load current 25 & 40 A @1200 VDC
 Load voltage 1200 VDC
 Isolation voltage 2500 VRMS
 Fast switching response
 Normal Open Type
 Chassis mounting /Panel Mount Switches
 High voltage SSR based on IGBT Technology
 LED Indicator showing relay ON status
 In-built free wheeling diode across power device



Input Specifications

| Description | Suffix- 12 | Suffix- 24 |
|----------------------------------|------------|------------|
| Control Voltage | 12VDC | 24 VDC |
| Nominal Control Voltage Range | 8-16 VDC | 20-28 VDC |
| Minimum Turn-On voltage | 8VDC | 20 VDC |
| Minimum Turn-Off Voltage | 1.0VDC | 1.0 VDC |
| Input Current at Nominal Voltage | 15mA | 15 mA |
| Turn-On Time (msec) | 1.5 | 1.5 |
| Turn-Off Time (msec) | 1.5 | 1.5 |

***For Input Control voltage 3-32VDC NO Suffix**

Output Specifications

| | 25 Amps SDD-1200-25- 12/24 | 40 Amps SDD-1200-40-12/24 |
|--|-------------------------------|------------------------------|
| Operating Voltage | 0 - 1200 VDC | 0 – 1200VDC |
| Max. Transient Over voltage VPK | 1200 | 1200 |
| Max. Off State Leakage Current @ rated voltage | 0.3mA | 0.3mA |
| Max. Load Current | 25 Adc | 40 Adc |
| Min. Load Current | 20 mA | 20 mA |
| Max surge current Adc 10ms | 75 Adc | 120 Adc |
| Max. On- state Voltage Drop @ Rated current (VDC) | 1.6 | 1.6 |
| Thermal Resistance Junction to Case | 0.4 °C/W | 0.25°C/W |
| Collector to Emitter Saturation Voltage $I_C = 25A$ $V_{GE} = 15V$ $T_C = 125\text{ °C}$ | 2.15 V | 2.9 V |

General Specifications

| | |
|---|----------------------------|
| Dielectric Strength Input/ Output/ Base | 2500 VRMS |
| Min Insulation Resistance | 10 ⁹ Ohm |
| Max. Capacitance Input/ Output | 50pf |
| Ambient Operating Temperature range | - 30 to 80°C |
| Ambient Storage Temp range | - 40 to 125 °C |
| Encapsulation | thermally conductive Epoxy |
| Weight | 100 gms |

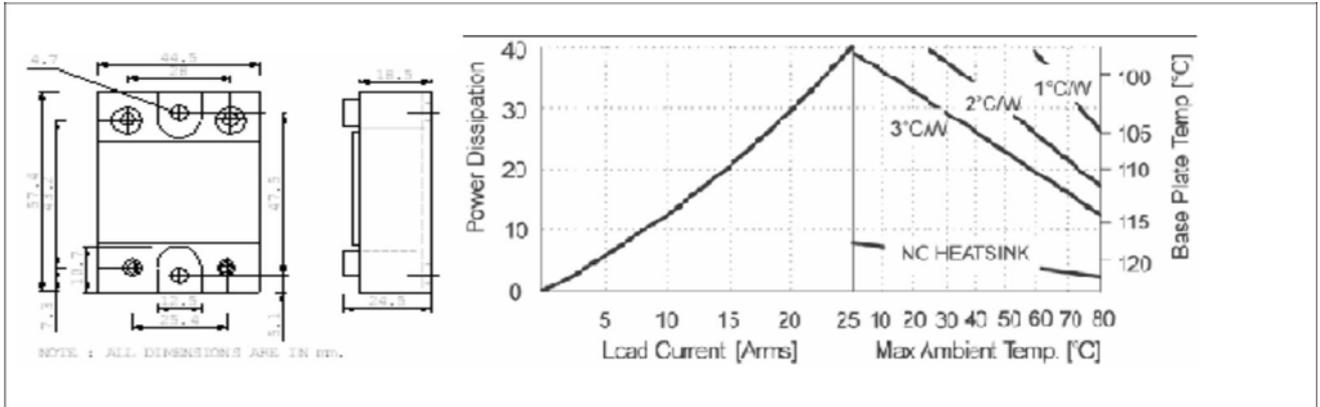
All parameters at 25°C unless otherwise specified
In-built freewheeling diode across the power device.

Note: Inductive loads should be diode suppressed.

All loads are inductive even ones that are not so labeled. When turned off an inductive load will produce harmful transient voltages. The more perfect the switch the larger the transient voltages. The IGBT output is so nearly an ideal switch that the transient voltages produced by seemingly 'non-inductive' loads can cause damage if not suppressed. Diodes should be fast recovery type with PIV rated greater than supply voltage.

Dimensions

THERMAL DERATING CURVE



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